GS324

Low Power Quad Operational Amplifiers

Product Description

The GS324 consists of four independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide range of voltages.

Operation from split power supplies is also possible and the low power supply current drains in independent of the magnitude of the power supply voltage.

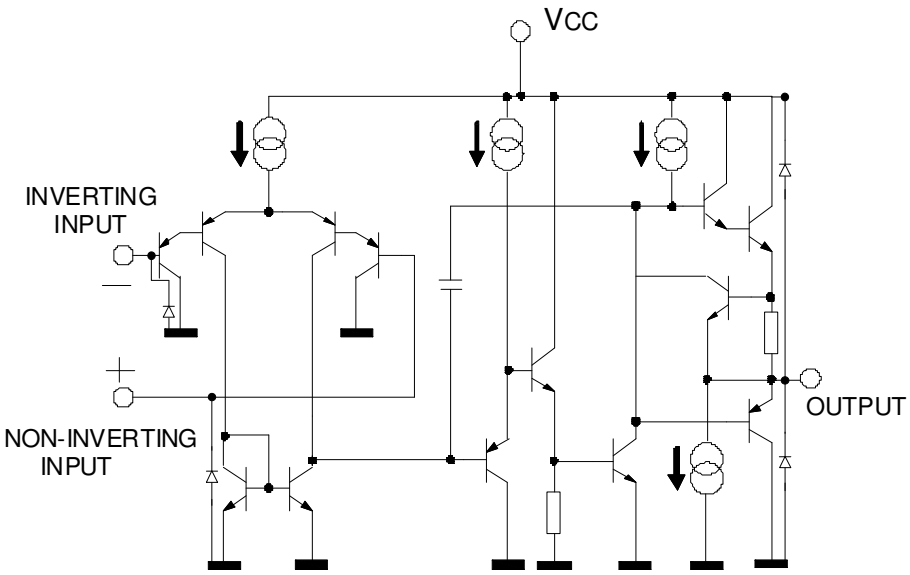
Application areas include transducer amplifiers, DC gain blocks and all the conventional op amp circuits, which now can be more easily implemented in single power supply systems.

For example, the GS324 can be directly operated off of the standard +5V power supply voltage which is used in digital systems and will easily provide the required interface electronics without requiring the additional±15V power supplies.

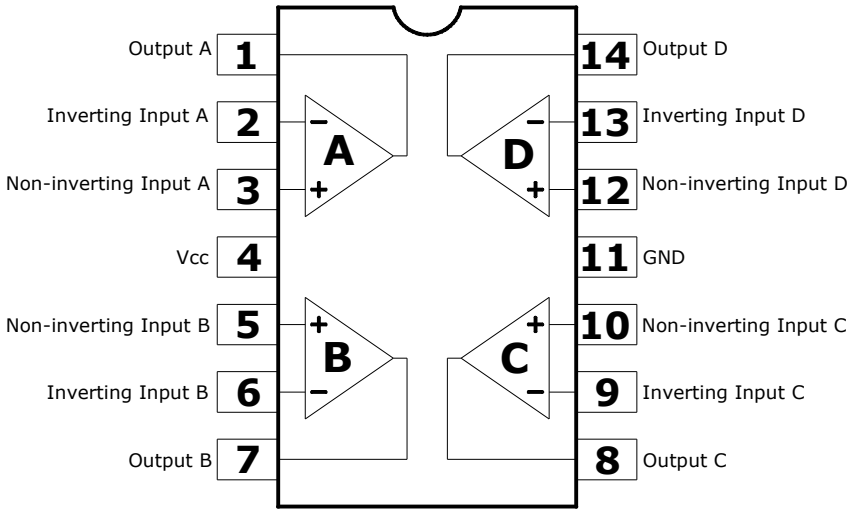
Features

- Wide range of supply voltages 3V to 32V
- Low supply current drain independent of Supply
- Supply Current 0.7mA TYP.
- Low input biasing current
- Low input offset voltage and offset current
- Input common-mode voltage range includes ground
- Differential input voltage range equal to the power supply voltage
- DC voltage gain: 100V/mV TYP.
- Internally frequency compensation
- RoHS Compliant, 100%Pb & Halogen Free
- ESD Protection(2KV) between V+/V- and GND

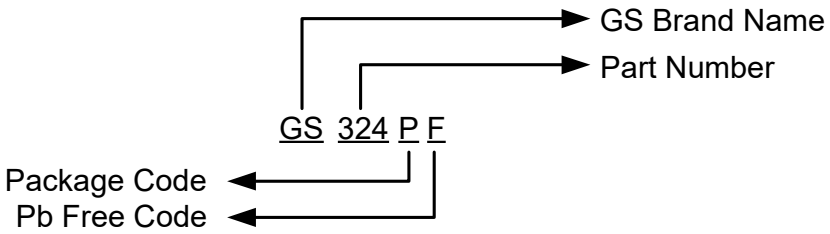
Block Diagram



Pin Assignments

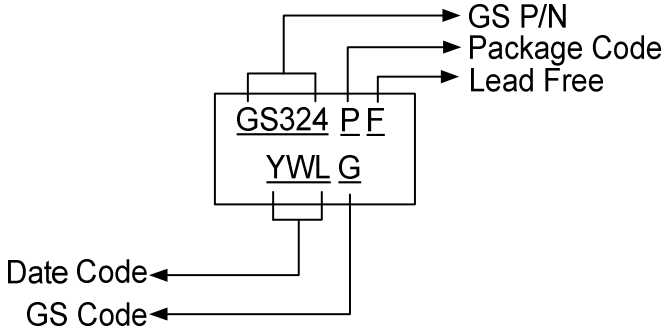


Ordering Information



Device	Package	Quantity Reel
GS324SF	SOP-14	4000 PCS

Marking Information



Absolute Maximum Ratings

Symbol	Parameter	Value		Unit
V_{CC}	Single Supply	32		V
V_{CC}, V_{EE}	Split Supply	±16		V
V_{IDR}	Input Differential Voltage Range	±32		V
I_{OS}	Output Short-circuit to GND	Continuous		
T_J	Junction Temperature	150		ºC
T_{STG}	Storage Temperature Range	-65 to +150		ºC
T_A	Operating Ambient Temperature Range	-40 to 85		ºC
θ_{JA}	Junction to Ambient Thermal Resistance	SOP-14	150	ºC/W
θ_{JC}	Junction to Case Thermal Resistance	SOP-14	23	ºC/W
ESD	ESD Rating (HBM)	2K		V

Electrical Characteristics

at specified free-air temperature, V_{CC}=5V (Unless Otherwise Noted)

Symbol	Parameter	Test Conditions*		Min	Typ	Max	Unit
V_{IO}	Input offset voltage	V_{CC}=5V to Max. V_{IC}=V_{ICR} min, Vo=1.4V	25ºC		2	3	mV
			Full range			5	
αV_{IO}	Average temperature coefficient of input offset voltage		Full range		7		µV/ºC
I_{IO}	Input offset current	Vo=1.4V	25ºC		2	50	nA
			Full range			150	
αI_{IO}	Average temperature coefficient of input offset current		Full range		10		pA/ºC
I_{IB}	Input bias current	Vo=1.4V	25ºC		20	250	nA
			Full range			500	
V_{ICR}	Common-mode input voltage range	V_{CC} =5V to MAX	25ºC	0 to V_{CC}-1.5			V
			Full range	0 to V_{CC}-2			
V_{OH}	High-level output voltage	R_L≥2kΩ	25ºC	V_{CC} -1.5			V
		V_{CC}=MAX, R_L=2kΩ	Full range	26			
		V_{CC}=MAX, R_L≥10kΩ	Full range	27	28		
V_{OL}	Low-level output voltage	R_L≥10kΩ	Full range		5	20	mV

Symbol	Parameter	Test Conditions*		Min	Typ	Max	Unit
A_{VD}	Large-signal differential voltage amplification	V_{CC}=15V Vo=1V to 11V R_L≥2kΩ	25ºC	25	100		V/mV
			Full range	15			
CMRR	Common-mode rejection ratio	V_{CC}=5V to MAX V_{IC}=V_{ICR} min	25ºC	65	80		dB
K_{SVR}	Supply voltage rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$)	V_{CC}=5V to MAX	25ºC	65	100		dB
V_{O1}/V_{O2}	Crosstalk attenuation	f=1kHz to 20kHz	25ºC		120		dB
Io	Output current	V_{CC}=15V, V_{ID}=1V, Vo=0V	25ºC	-20	-30		mA
			Full range	-10			
		V_{CC}=15V V_{ID}=-1V, Vo=15V	25ºC	10	20		
			Full range	5			
		V_{ID}=-1V, Vo=200mV	25ºC	12	30		µA

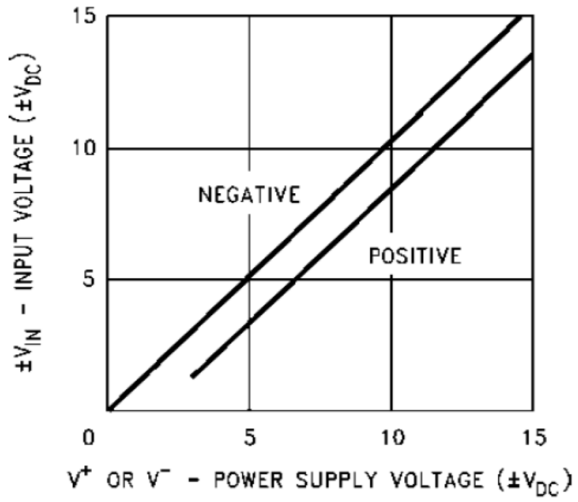
Electrical Characteristics (Continue)

Symbol	Parameter	Test Conditions*		Min	Typ	Max	Unit
I_{OS}	Short-circuit output current	V_{CC} at 5V, GND at -5V, Vo=0V	25ºC		±40	±60	mA
I_{CC}	Supply current (two amplifiers)	Vo=2.5V, No load	Full range		1.5	3	mA
		V_{CC}=MAX, Vo=0.5Vcc, No load	Full range		0.7	1.2	

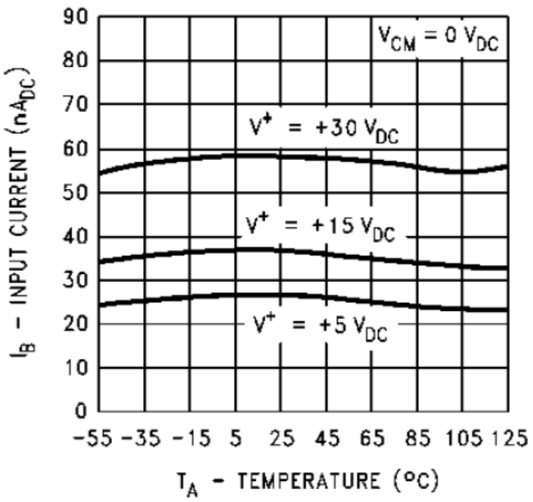
*All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. “MAX” V_{CC} for testing Purposes is 30V. Full range is -40 ºC to 85 ºC.

Typical Performance Characteristics

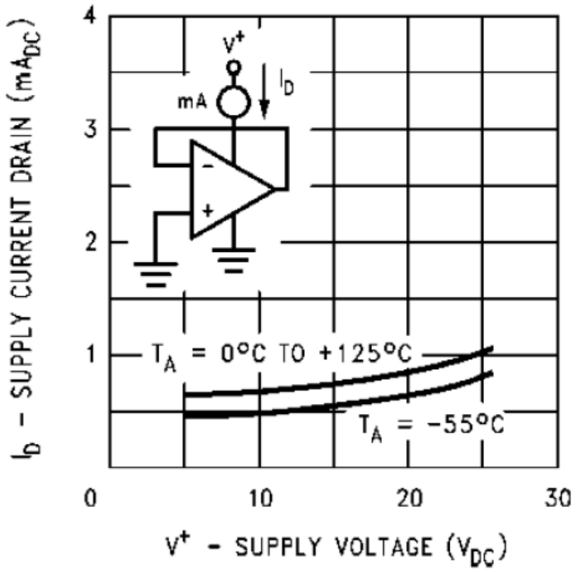
Input Voltage Range



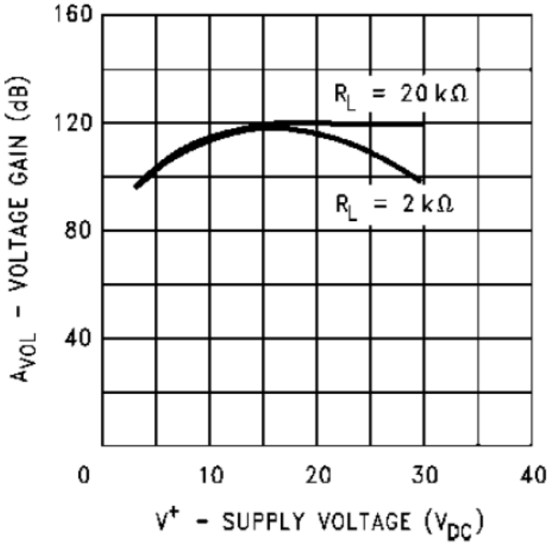
Input Current



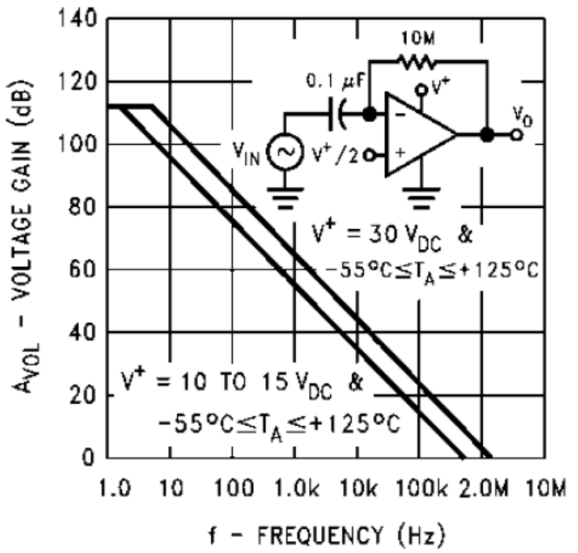
Supply Current



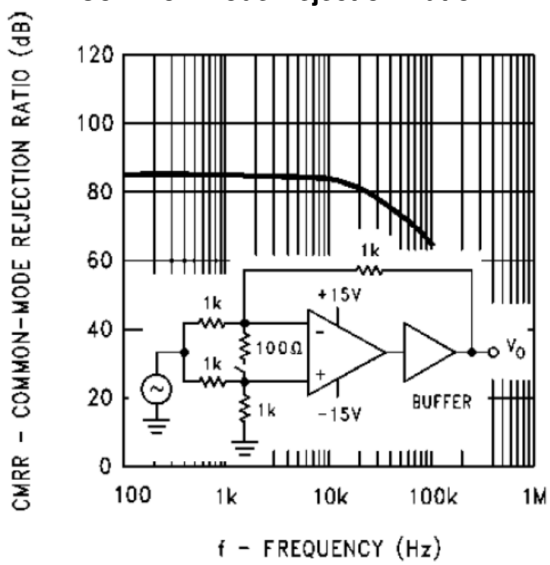
Voltage Gain



Open Loop Frequency Response

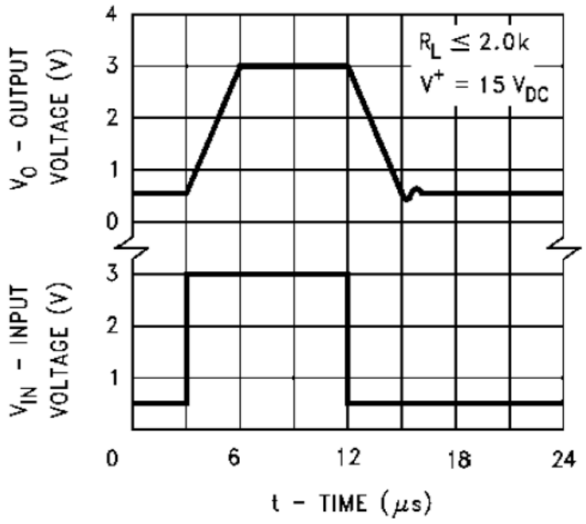


Common Mode Rejection Ratio

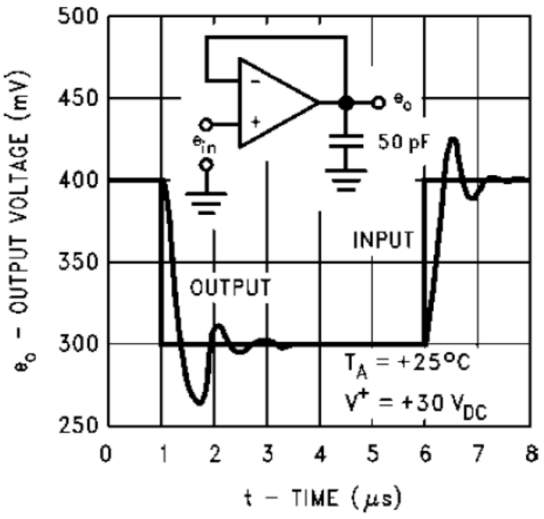


Typical Performance Characteristics (Continue)

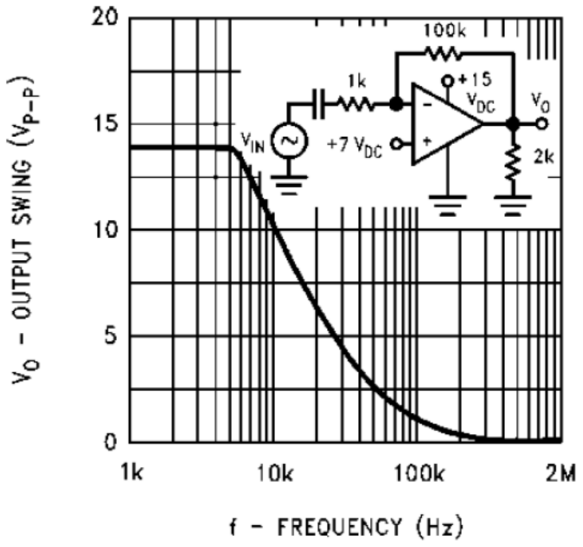
Voltage Follower Pulse Response



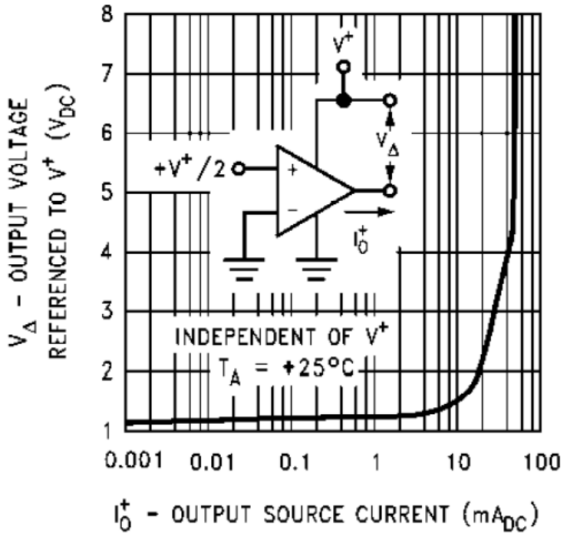
Voltage Follower Pulse Response (Small Signal)



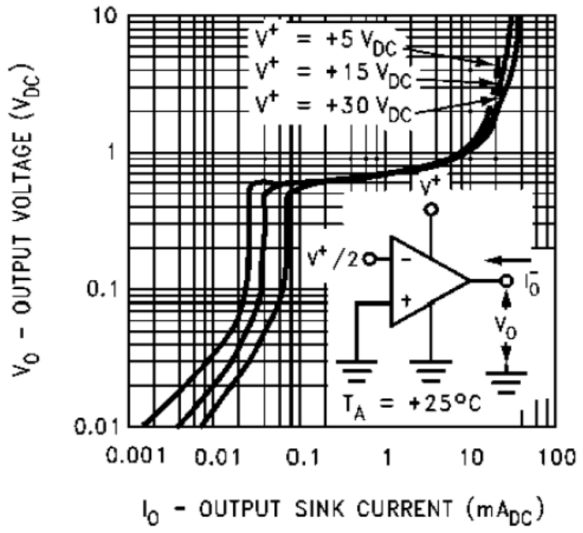
Large Signal Frequency Response



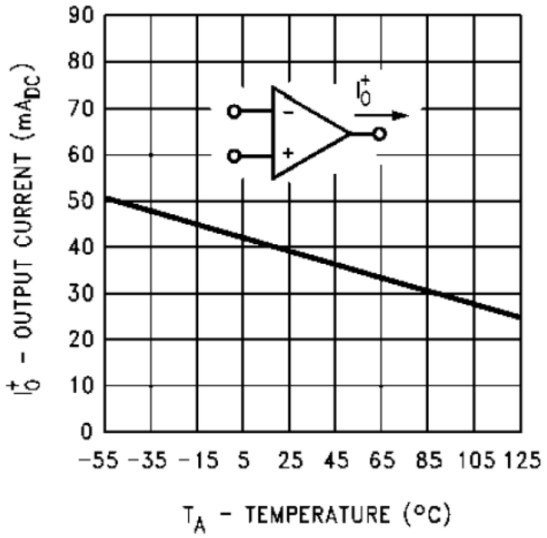
Output Characteristics Current Sourcing



Output Characteristics Current Sinking

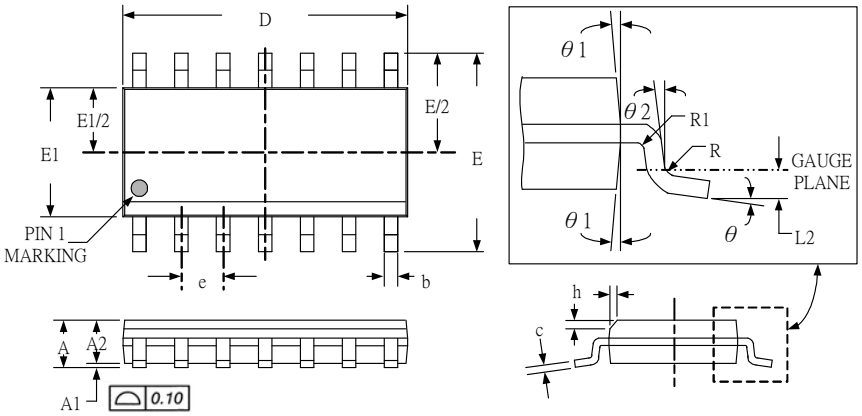


Current Limiting



Package Dimension

SOP-14 PLASTIC PACKAGE



Dimensions				
SYMBOL	Millimeters		Inches	
	MIN	MAX	MIN	MAX
A	1.35	1.75	.053	.069
A2	1.25	1.65	.049	.065
b	0.31	0.51	.012	.020
b1	0.28	0.48	.011	.019
c	0.17	0.25	.007	.010
A1	0.1(MAX)		0.004(MAX)	
D	8.65 (TYP)		.341 (TYP)	
E	6.00 (TYP)		.236 (TYP)	
E1	3.90 (TYP)		.154 (TYP)	
e	1.27 (TYP)		.050 (TYP)	
L	0.40	1.27	.016	.050
L1	1.04 (TYP)		.041 (TYP)	
L2	0.25 (TYP)		.010 (TYP)	
R	0.07	-	.003	-
R1	0.07	-	.003	-
h	0.25	0.50	.010	.020
θ	0°	8°	0°	8°
θ1	5°	15°	5°	15°
θ2	0°	-	08	-
Lead Coplanarity	-	0.1	-	.004

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